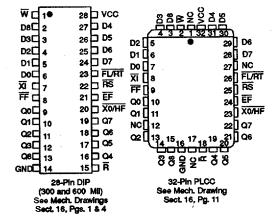
50E D

## **FEATURES**

- · First-in, first-out memory-based architecture
- Flexible 1024 x 9 organization
- Low-power HCMOS technology
- Asychronous and simultaneous read/write
- Bidirectional applications
- Fully expandable by word width or depth
- · Empty and full warning flags
- Half-full flag capability in single-device mode
- Retransmit capability
- Available in 50ns, 65ns, 80ns, and 120ns access times
- Industrial temperature range -40°C to +85°C available, designated N, in 50ns, 65ns, 80ns, and 120ns access times

## PIN ASSIGNMENT



## PIN DESCRIPTION

W - WRITE

Ŕ - READ

RS - RESET FL/RT

First Load/Retransmit

- Data In D<sub>0-8</sub> - Data Out Q<sub>0-8</sub>

X - Expansion In

XO/HF - Expansion Out/Half Full

FF - Full Flag

EF - Empty Flag

- 5 Volts  $V_{CC}$ 

GND - Ground

- No Connect NC

## DESCRIPTION

The DS2010 FIFO Chip implements a first-in, first-out algorithm featuring asynchronous read/write operations, full, empty, and half-full flags, and unlimited expansion capability in both word size and depth. The DS2010 is functionally and electrically equivalent to the

DS2009 512 x 9 FIFO, with the exceptions listed in the notes for DC Electrical Characteristics of the DS2009 data sheet. Refer to the DS2009 data sheet for detailed device description.